

DEVELOPMENT OF 250W EUV LIGHT SOURCE FOR HVM LITHOGRAPHY

EUVL Workshop 2016

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AGENDA

- Introduction
- Issue of EUV Light Source and History of Source Power-Up
- 250W Pilot System Development Update
 - Key Component Technologies Update
- Prototype LPP Source Systems Experiment Update
 - Proto Device #1
 - Proto Device #2
- For Future Development of 500W LPP Source
- Summary

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G10K

G20K

G41K

GT40A

GT60A

GT64A



1300

Laser Installed

900

Laser Installed

64% Market Share

400

Laser Installed

40% Market Share

700 Employees

25% Market Share

200 Employees

370 Employees

130

Laser Installed

15% Market Share

250 Employees

Gigaphoton's Growth

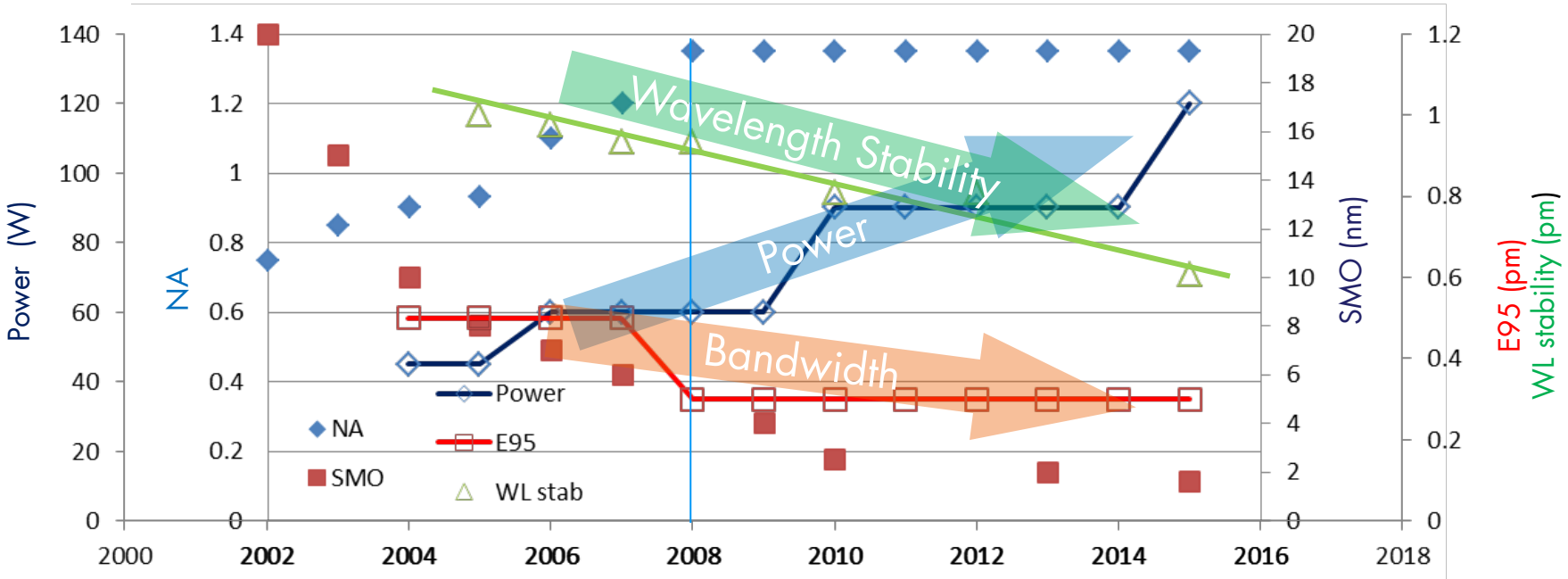
2000

2005

2010

2015

Improvement of ArF Laser Performance during Multiple-Exposure



New Fab will Open for Expanding Demand of DUV Laser



AGENDA

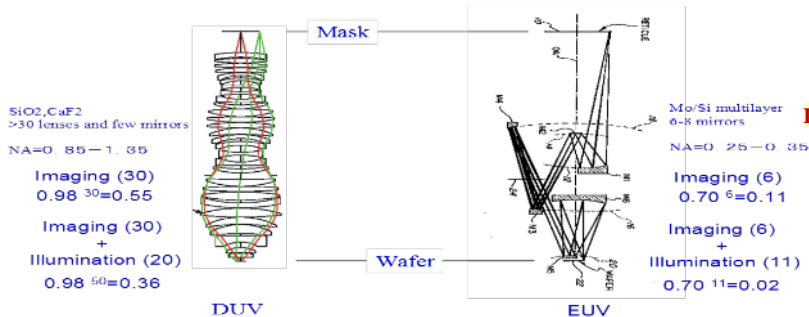
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Issue of EUV lithography (1)

EUV light transmittance is only 2% at 11 reflection mirror system

High power light source for HVM exposure tools is the **KEY** Issue

Demand: >250W at 1st stage HVM



Illumination Optics

- Optical design for minimizing the number of mirrors

Low reflectivity of Mo/Si mirror

Projection Optics

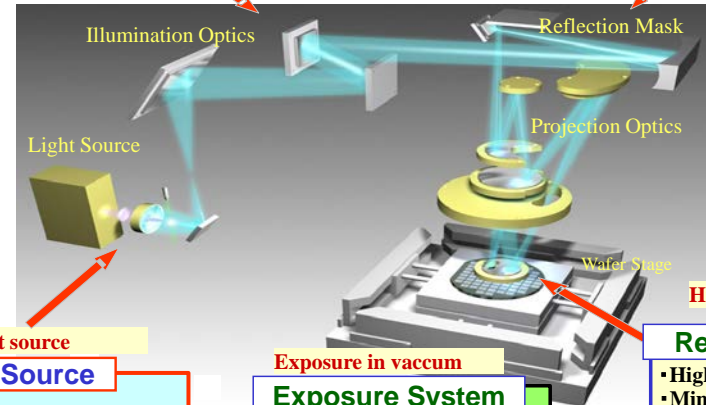
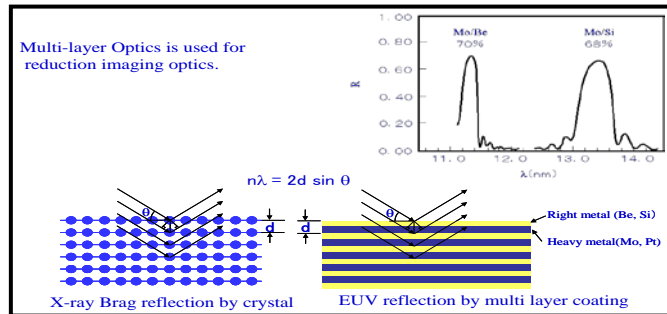
- High accuracy figuring
- Metrology
- Contamination control

Highly accurate mirror surface

Mask

- Low defect blanks
- Defect inspection
- Defect repair

Reflection mask



New light source

Light Source

- High power source
- Debris mitigation
- Low etandue

Exposure in vaccum

Exposure System

- Stage in vacuum
- Electrostatic chuck
- Accurate alignment

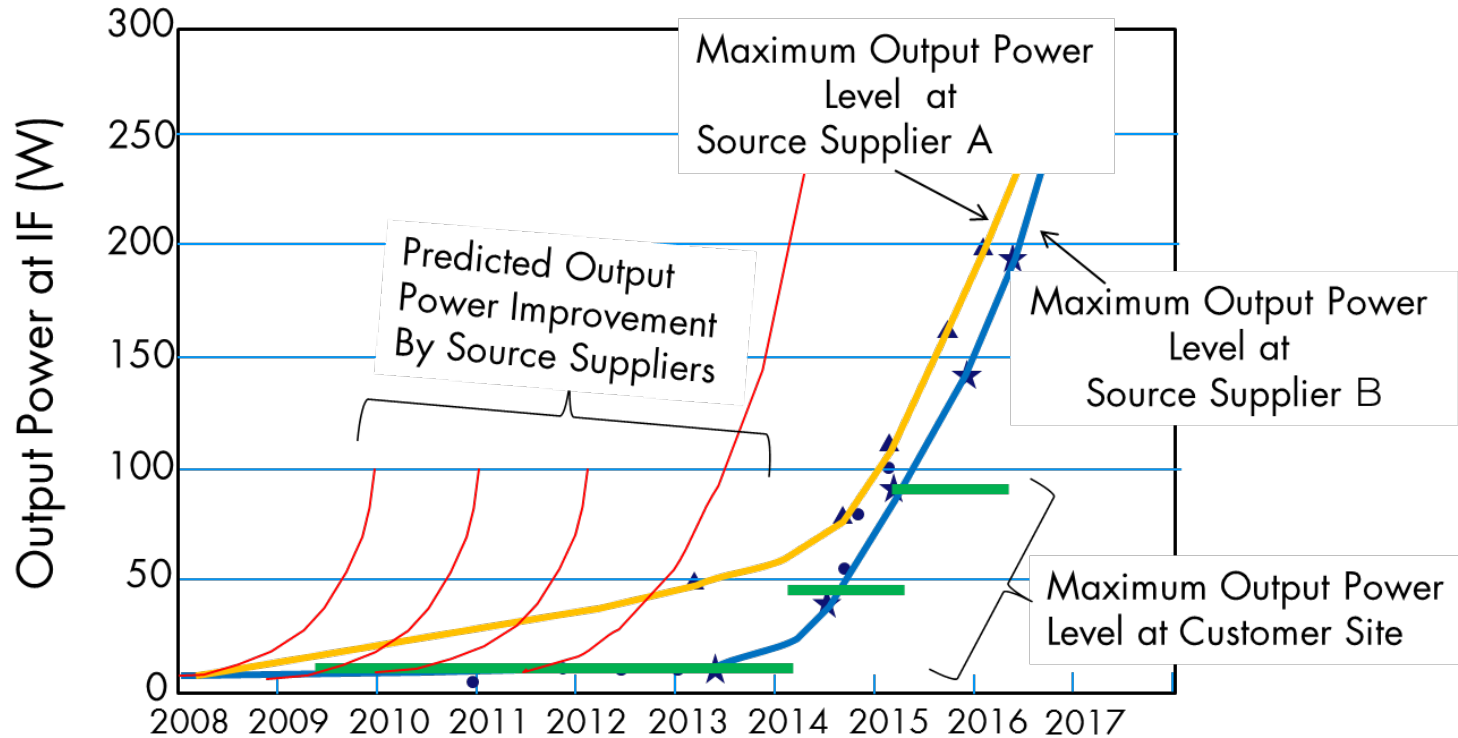
High sensitive resist

Resist

- High sensitivity
- Minimizing line edge roughness (LER)
- Low out gassing

Issue of EUV lithography (2)

History of EUV source output power improvement

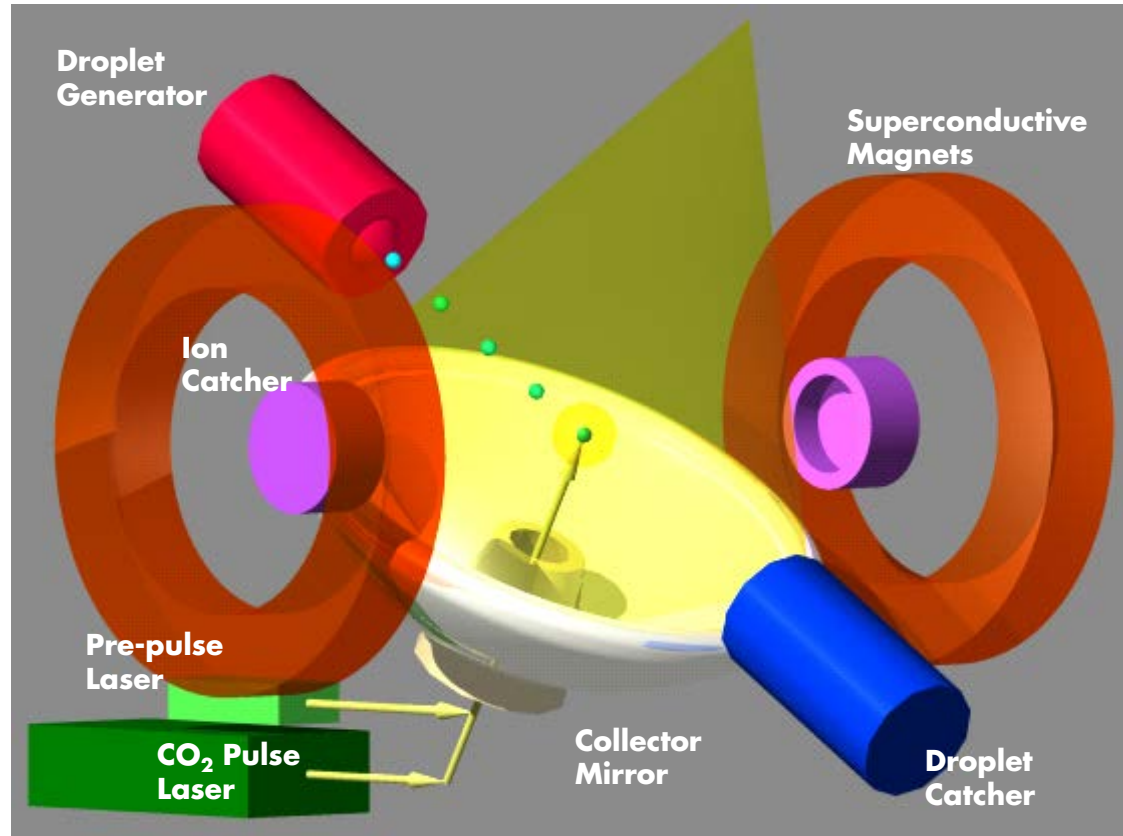


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Gigaphoton's LPP Light Source Concept

- High ionization rate and CE EUV tin (Sn) plasma generated by CO₂ and pre-pulse solid laser dual wavelength shooting
- Hybrid CO₂ laser system with short pulse high repetition rate oscillator and commercial cw-amplifiers
- Accurate shooting control with droplet and laser beam control
- Tin (Sn) debris mitigation with a super conductive magnetic field
- High efficient out of band light reduction with grating structured C1 mirror



Pilot and Proto Systems Configuration

Target System Specification

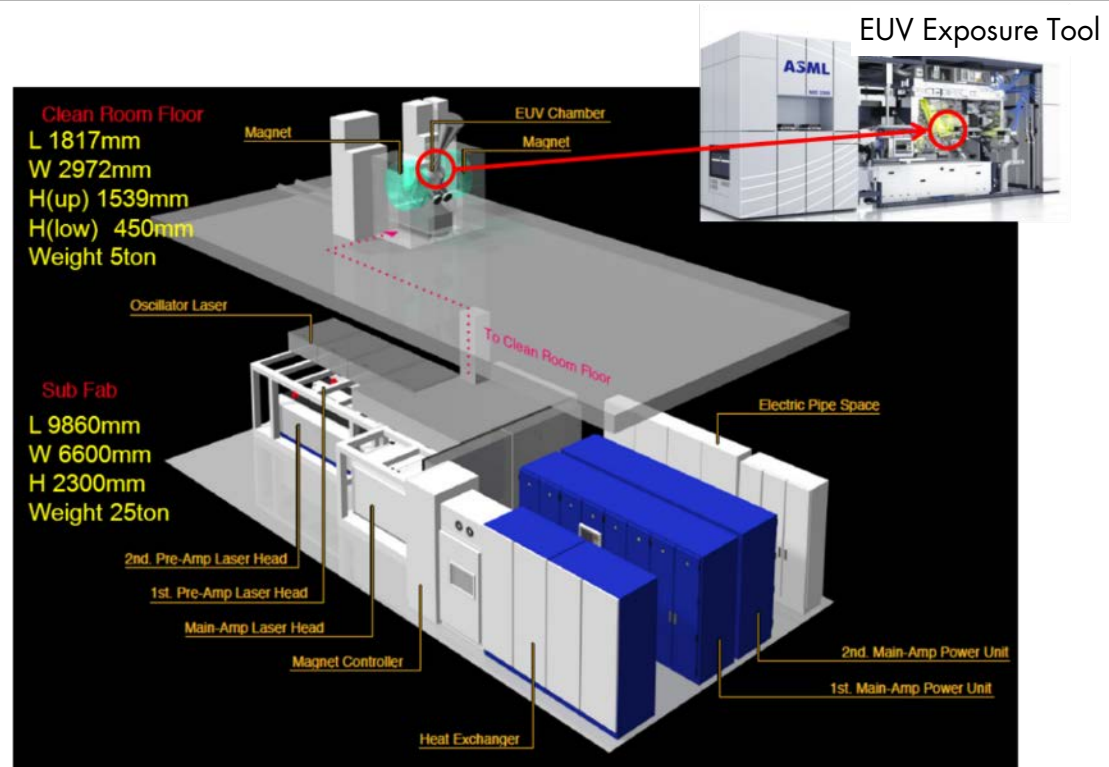
Operational Specification		Pilot #1	Proto #1	Proto #2
Target Performance	EUV Power	250 W	25 W	> 100 W
	CE	4%	3%	3.5%
	Pulse rate	100 kHz	100 kHz	100 kHz
	Output angle	62°upper (matched to NXE)	Horizontal	62°upper (matched to NXE)
	Availability	> 75%	1 week operation	1 week operation
Technology	Droplet generator	< 20 μm	20 – 25 μm	20 μm
	CO ₂ laser	27 kW	5 kW	20 kW
	Pre-pulse laser	picosecond	picosecond	picosecond
	Debris mitigation	> 3 month	validation of magnetic mitigation in system	10 days

Pilot #1 EUV Light Source for HVM

Layout of 250W EUV Light Source

First HVM Source will be 250W

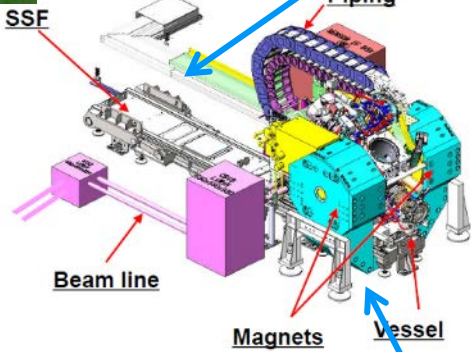
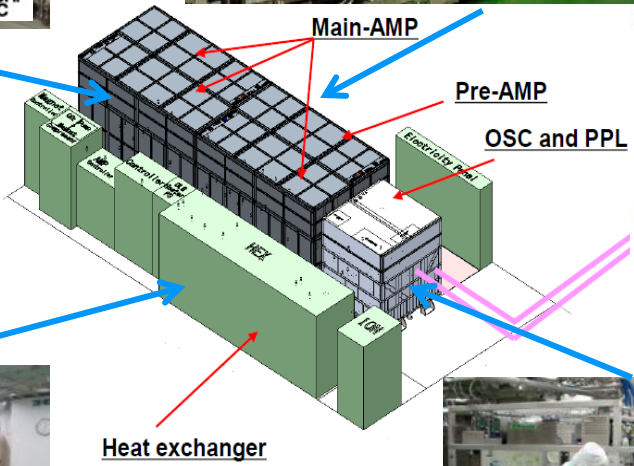
Operational specification (Target)		HVM Source	
Performance	EUV Power	> 250W	
	CE	> 4.0 %	
	Pulse rate	100kHz	
	Availability	> 75%	
Technology	Droplet generator	Droplet size	< 20mm
	CO2 laser	Power	> 20kW
	Pre-pulse laser	Pulse duration	psec
	Debris mitigation	Magnet, Etching	> 15 days (>1500Mpls)



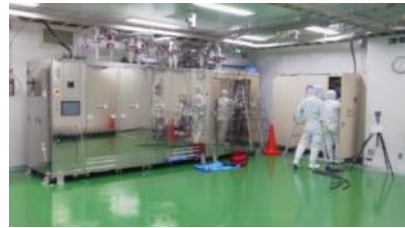
Pilot # 1: Picture of construction (2015.6 – 2016.1)



Driver laser



EUV chamber



Pilot # 1: Construction is Completed ! (2016.02)

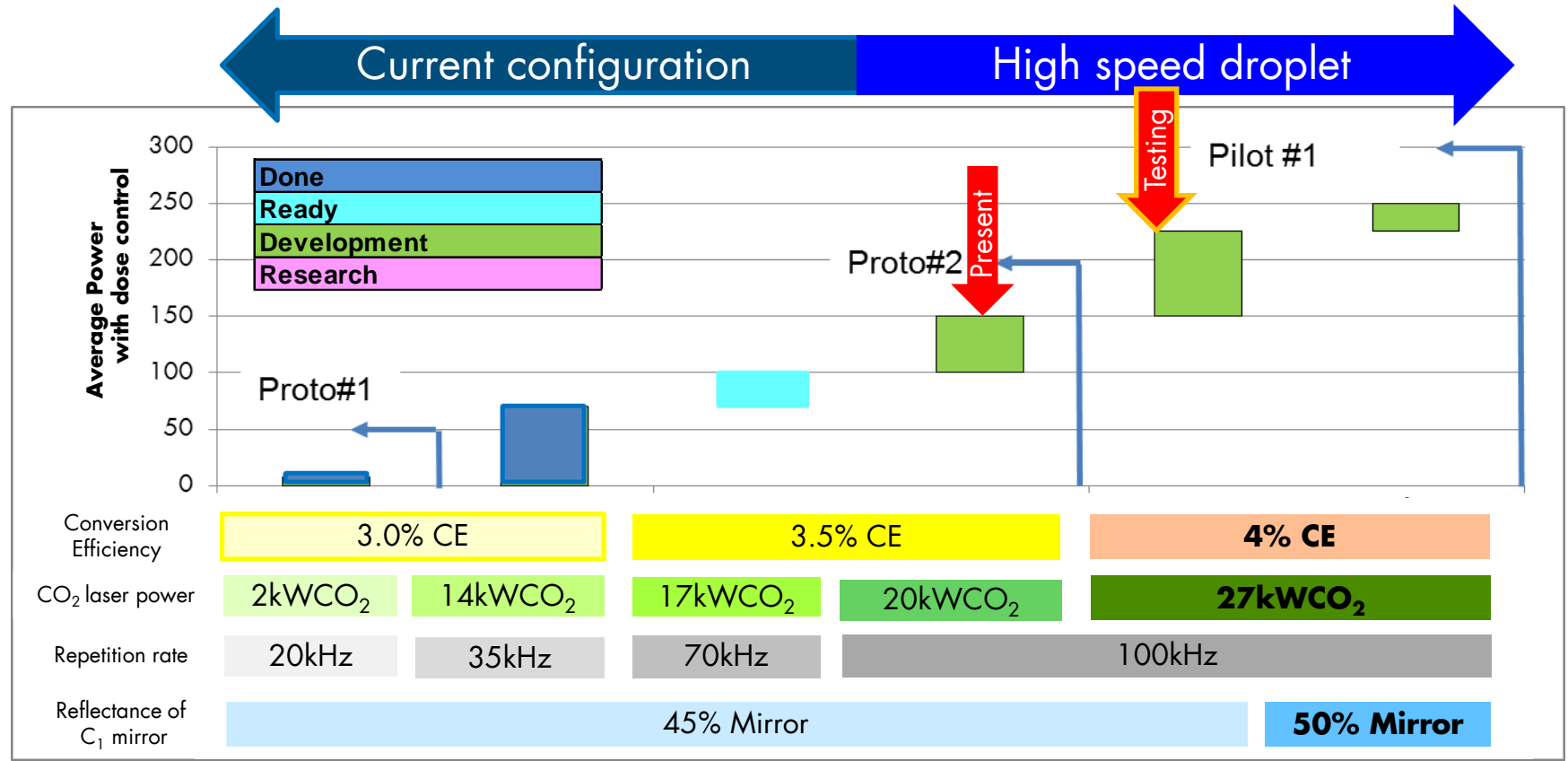
EUV chamber and Magnet



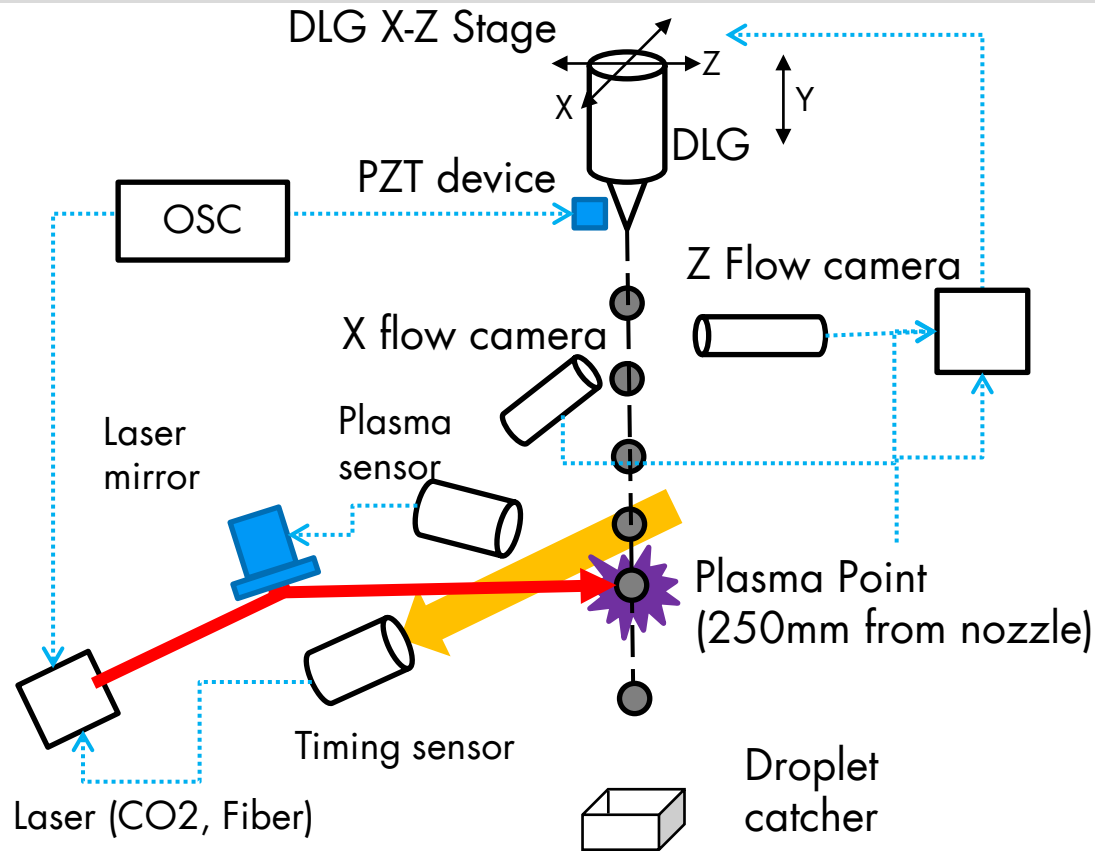
CO₂ driver laser system



Power-up Scenario



LPP EUV Source : Shooting Control System



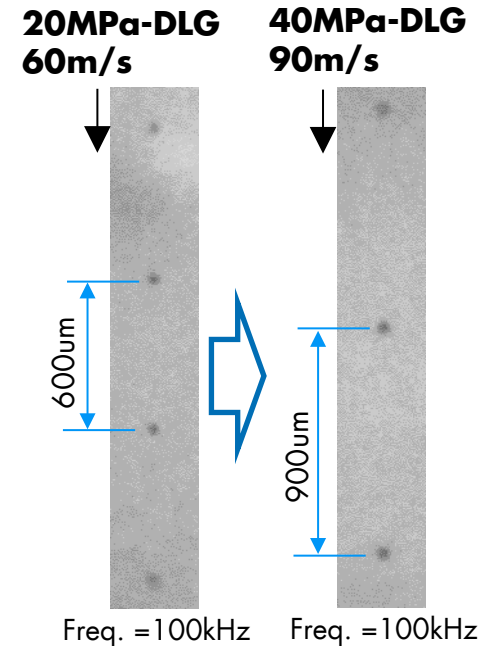
LPP EUV Source: Operation Desk



Droplet Generator technology (1)

High speed droplet generator was successfully released to Proto system

		2013 Jan Proto# 1	2014 Sep Proto#2	2015 Dec Proto#2 and Pilot# 1
Droplet speed	m/s	45	60	90
Back pressure	MPa	12	20	40
Repetition rate limit	kHz	50	80	>100
Status		Proven	Proven	Proven



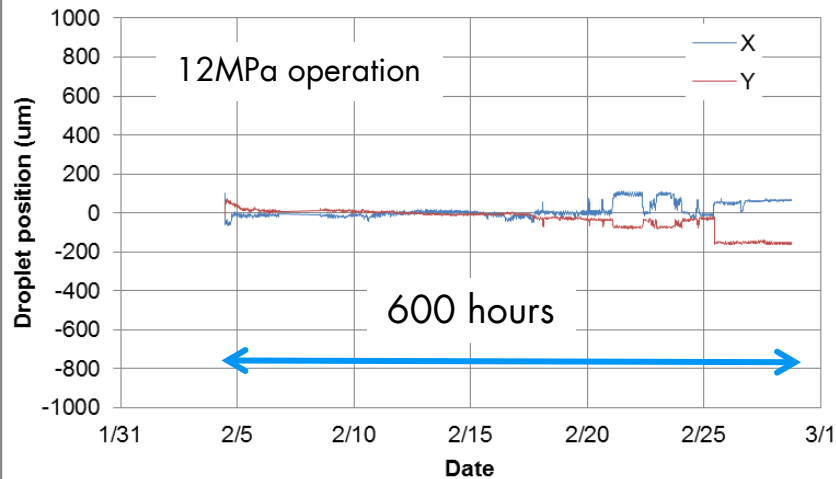
Droplet Status

New Data

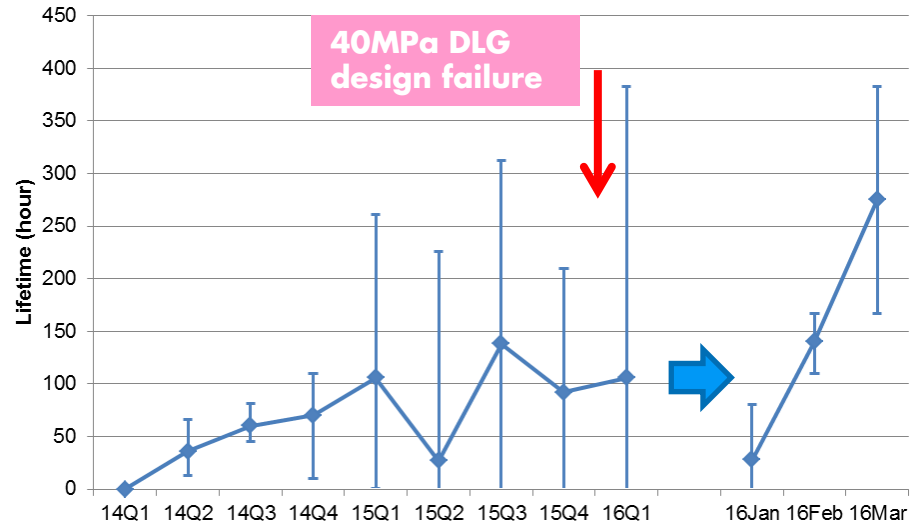
Droplet Generator technology (2)

- 600 hours lifetime in 12MPa was confirmed in test bench.
- Average lifetime in 40MPa is 260 hours at present.

Droplet performance w/o control in test bench



DLG lifetime in system

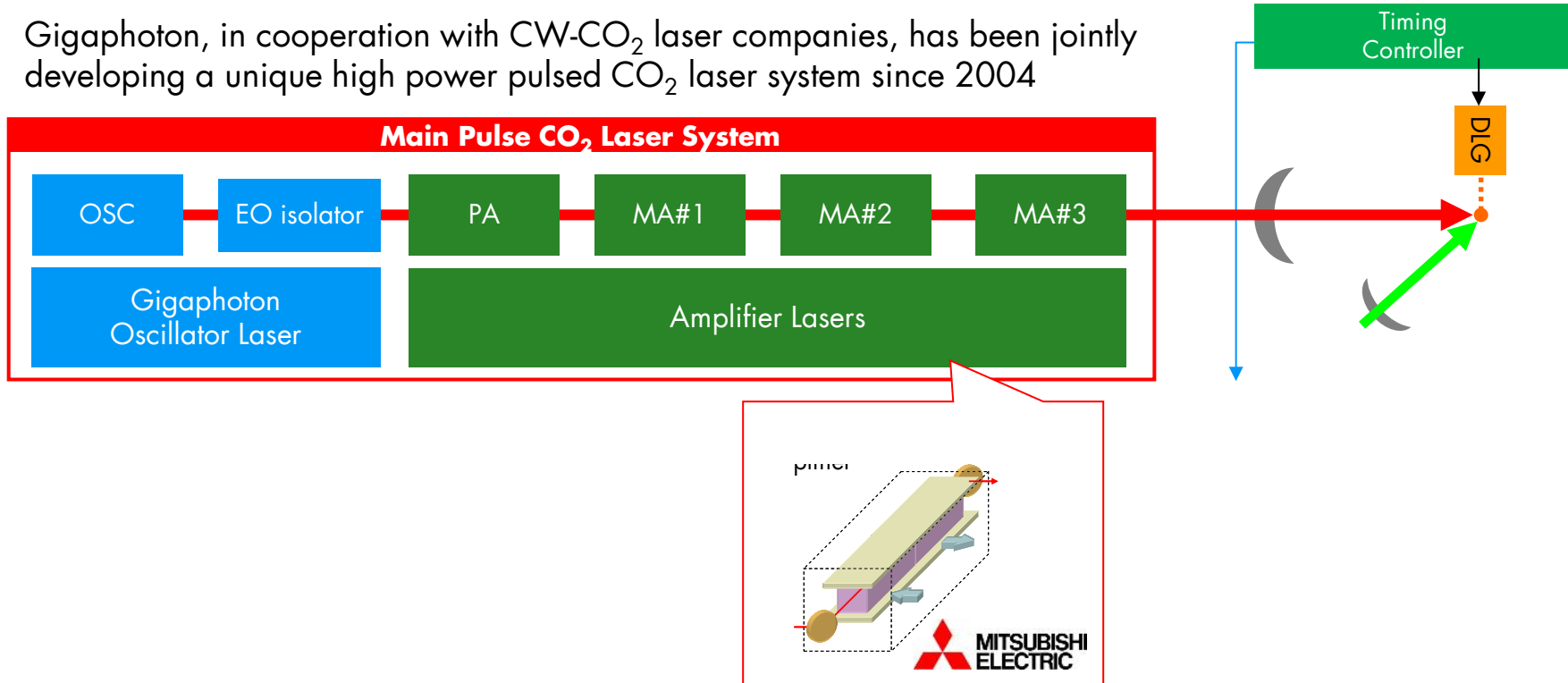


New Data

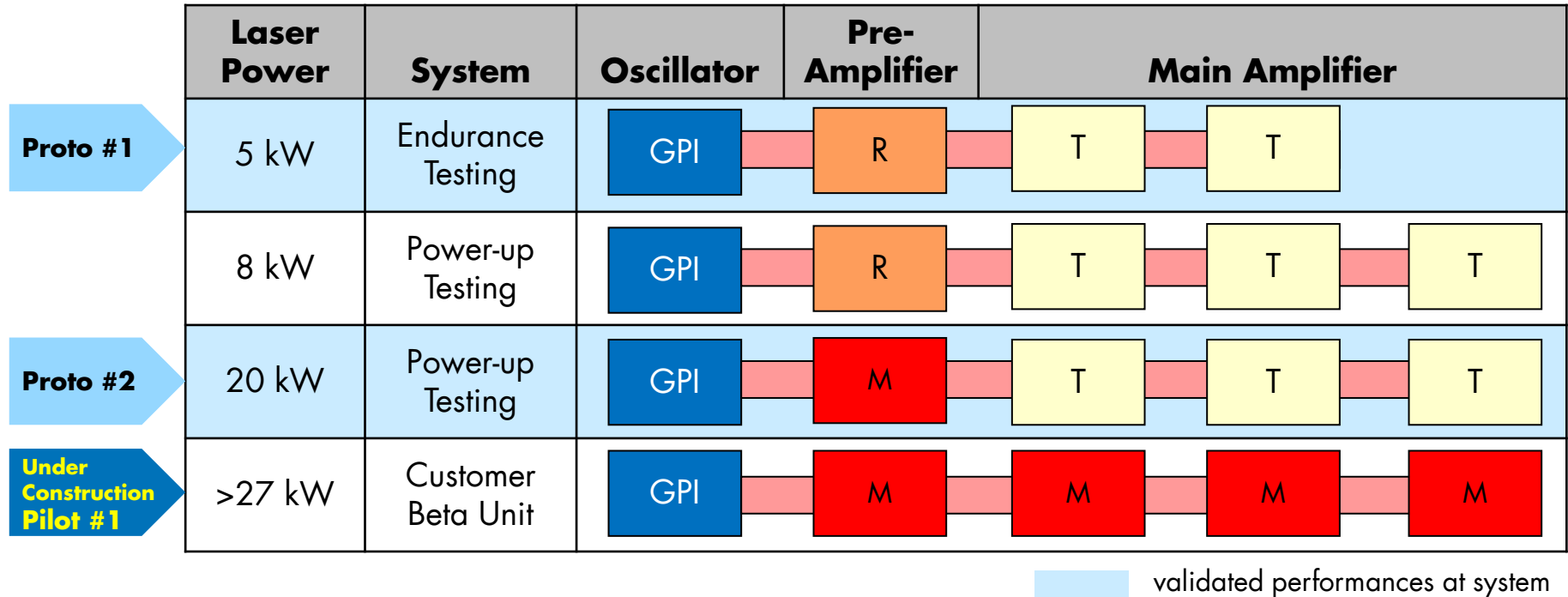
High Power CO₂ Laser Technology (1)

Driver Laser System

Gigaphoton, in cooperation with CW-CO₂ laser companies, has been jointly developing a unique high power pulsed CO₂ laser system since 2004

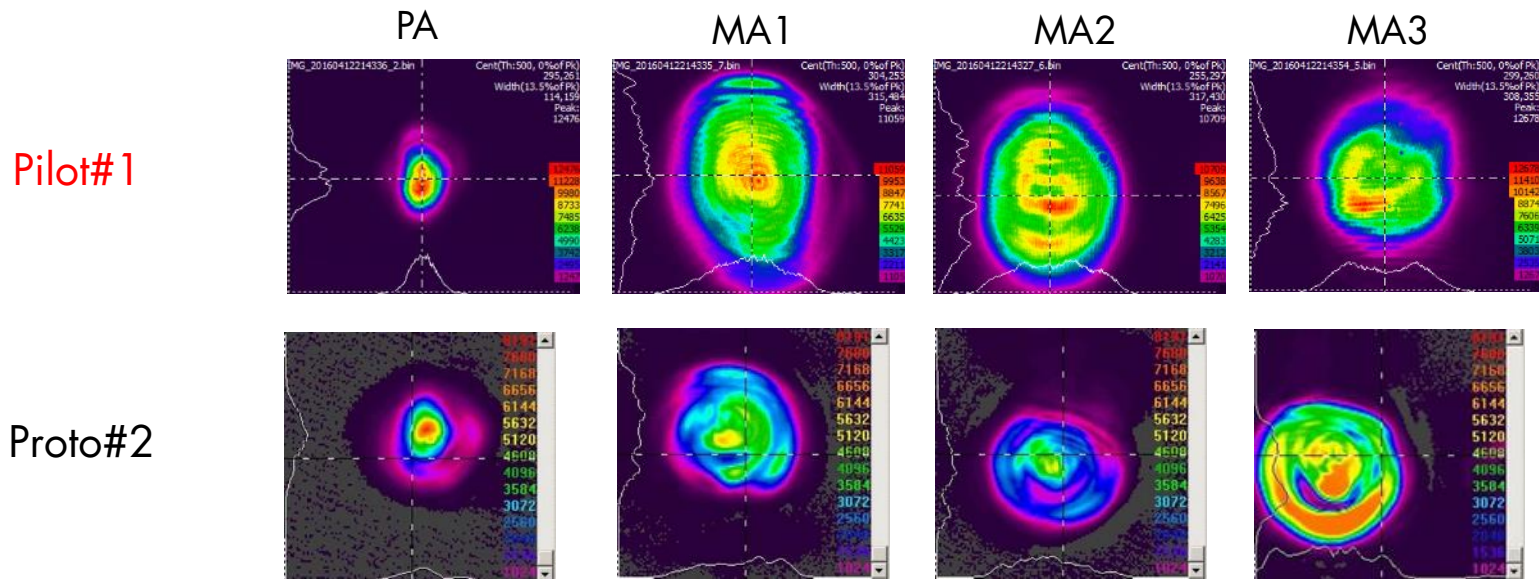


High Power CO₂ Laser Technology



Pilot # 1: CO₂ Laser System is Ramping-up (Apr.2016)

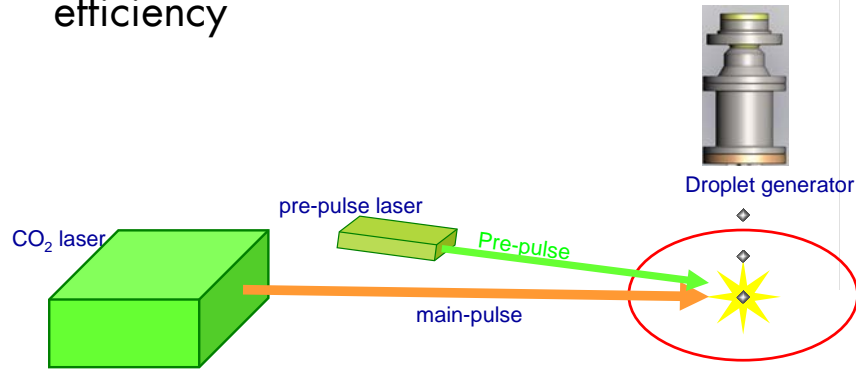
CO₂ Laser system beam profile in Pilot#1 is dramatically improved. It will contribute higher CE operation



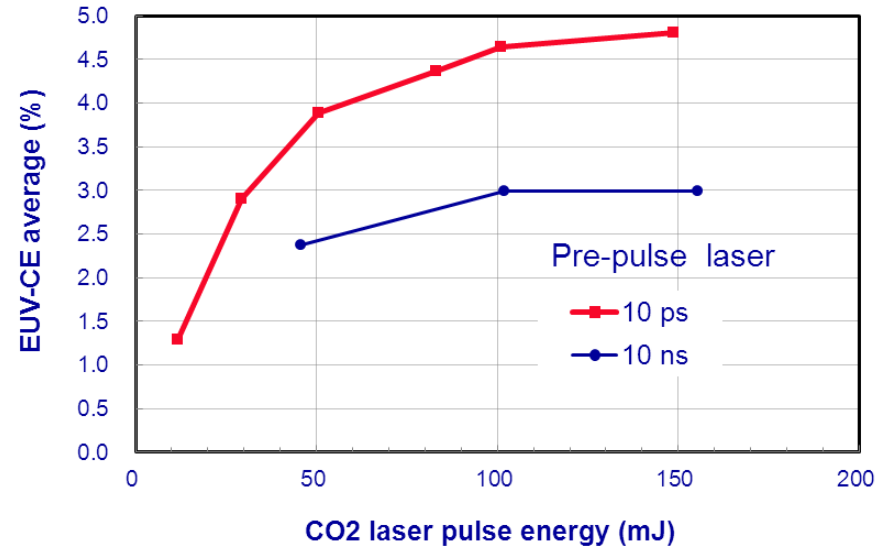
New Data

Pre-Pulse Technology (1)

- Based on basic physical consideration and experiments, Gigaphoton has chosen to adopt the pre-pulse technology since 2009
- In 2012 Gigaphoton discovered that shortening the pre-pulses duration dramatically enhance the conversion efficiency

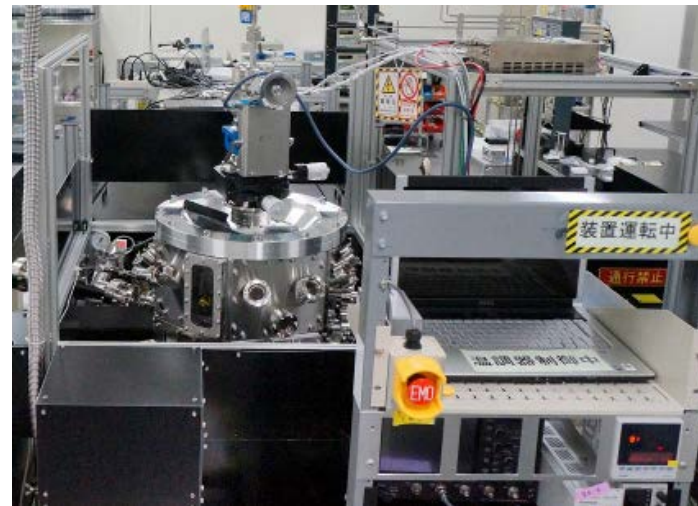
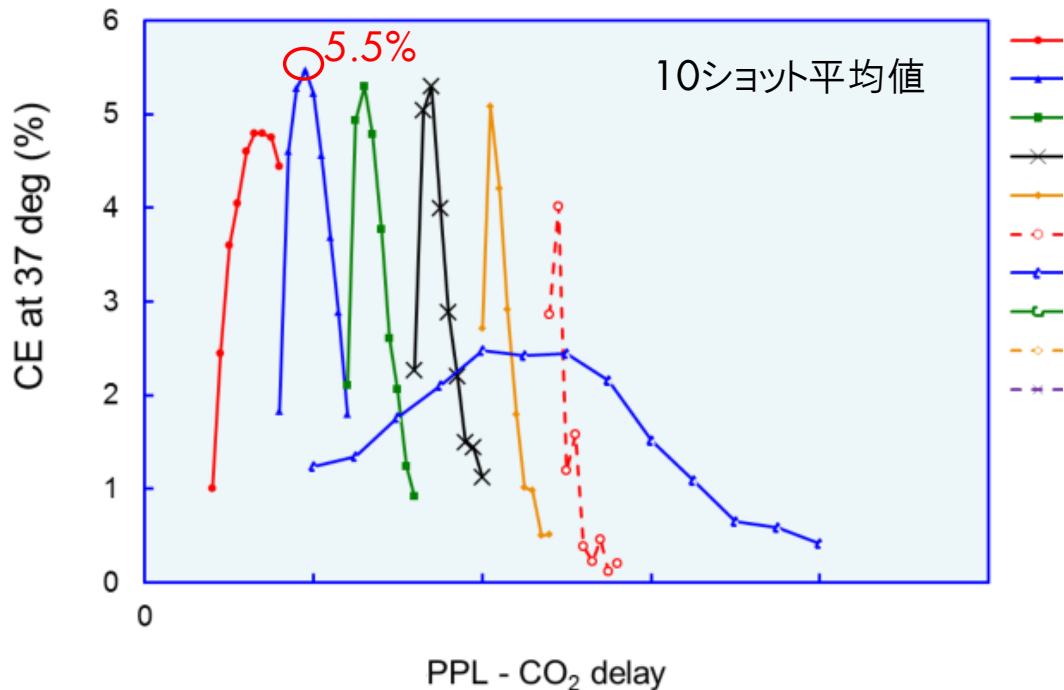


CO₂ pulse energy vs. EUV-CE



Pre-Pulse Technology (2)

In small experimental device, we observed **5.5% CE** under optimized condition. **17 % increase** from old champion data (CE=4.7%).



Experimental Device

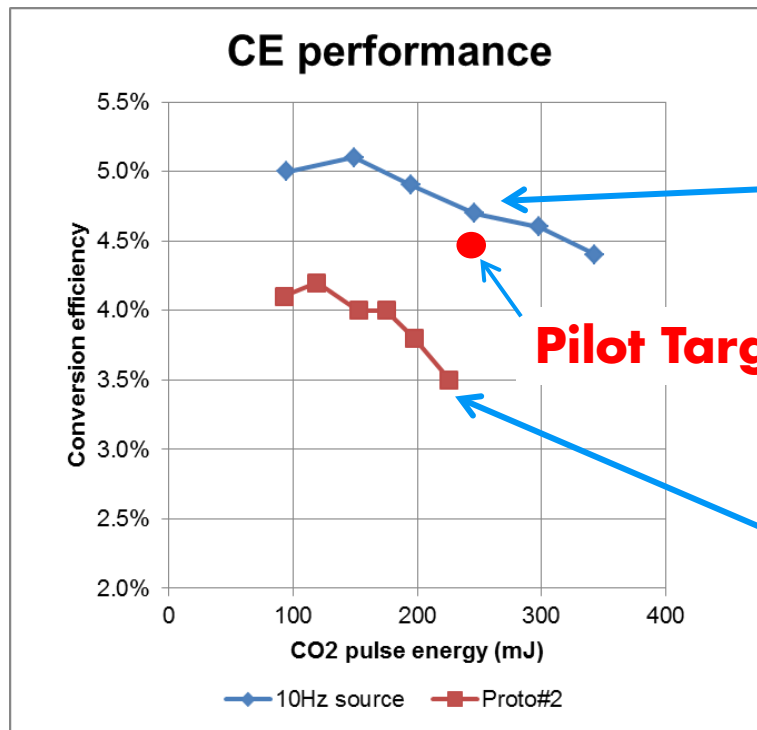
Pre-Pulse Technology (3)

- Issue

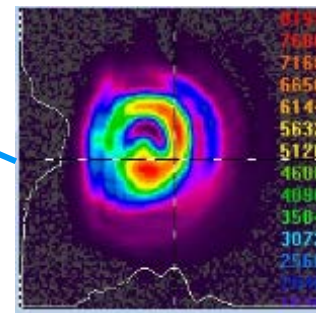
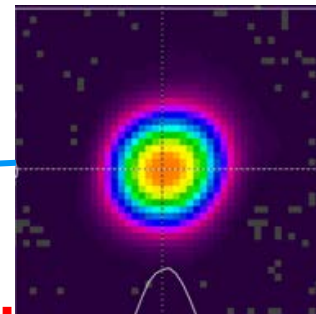
- » CE in Proto#2 is 1% lower than 10Hz source. This would be due to CO₂ laser beam inhomogeneity.

- Next Step

- » CO₂ laser beam homogeneity would be improved in Pilot#1 system.



CO₂ Laser Profile



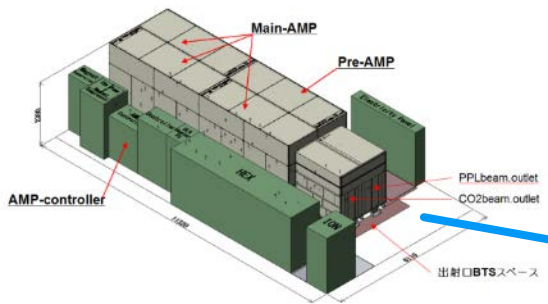
New Data

AGENDA

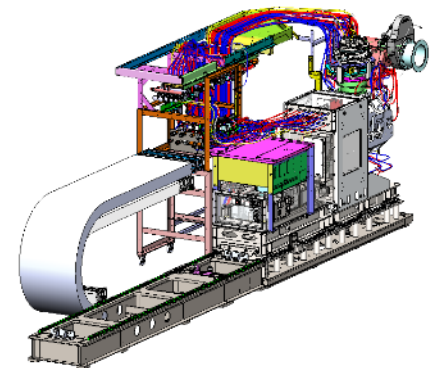
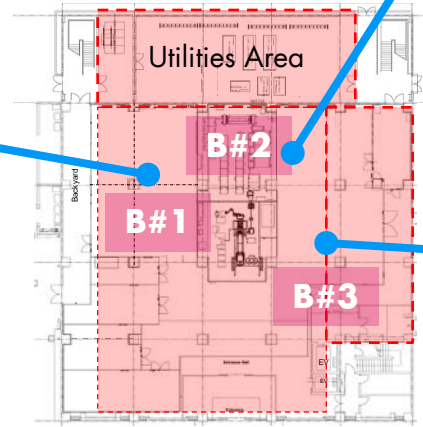
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Gigaphoton EUV Sources

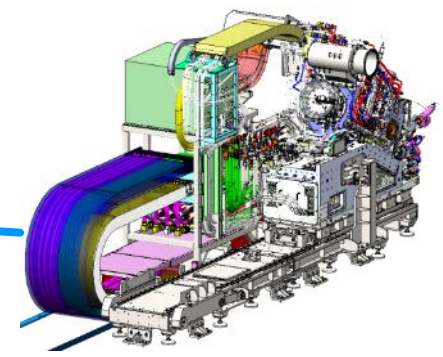
- 2 – proto system are in operation
- 1 – pilot system is under construction



Pilot #1 NEW
 (under construction)



Proto #1
 From Oct 2012



Proto #2
 From Nov 2013

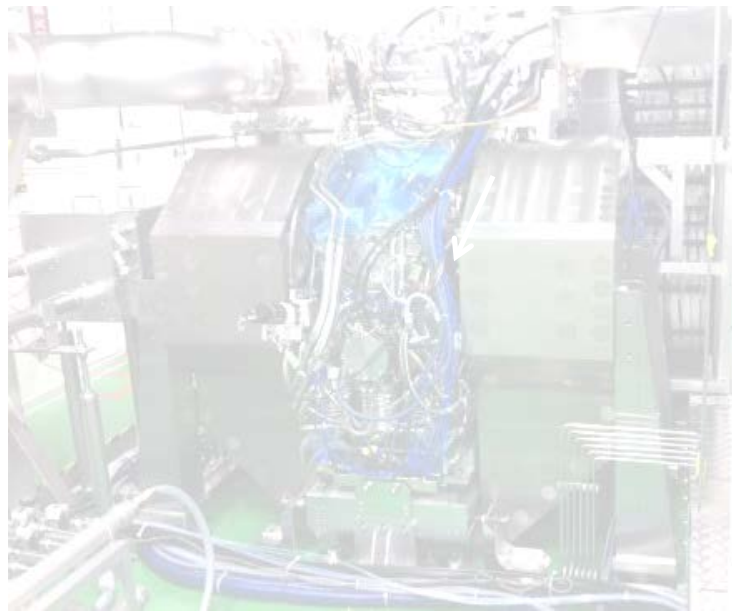
Gigaphoton's High Power EUV Light Source

Prototype high power EUV light source is in operation

Proto 1 Exposure & Mitigation test

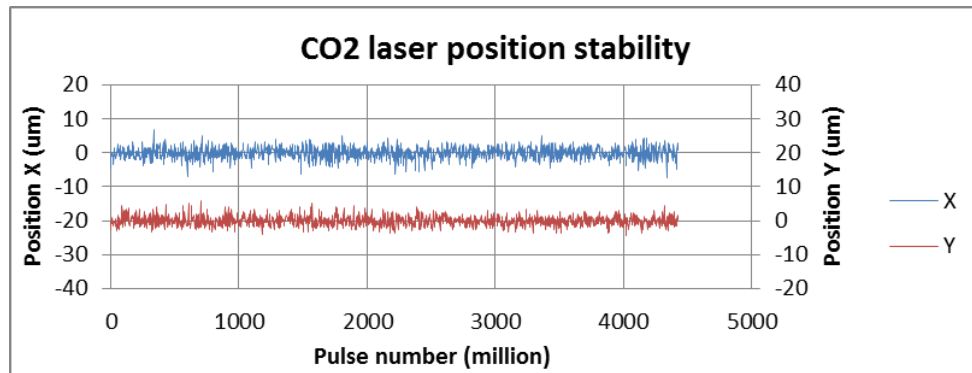
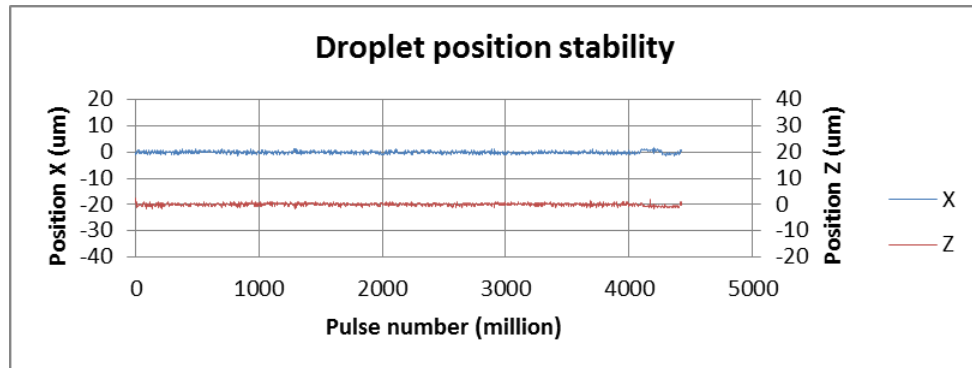
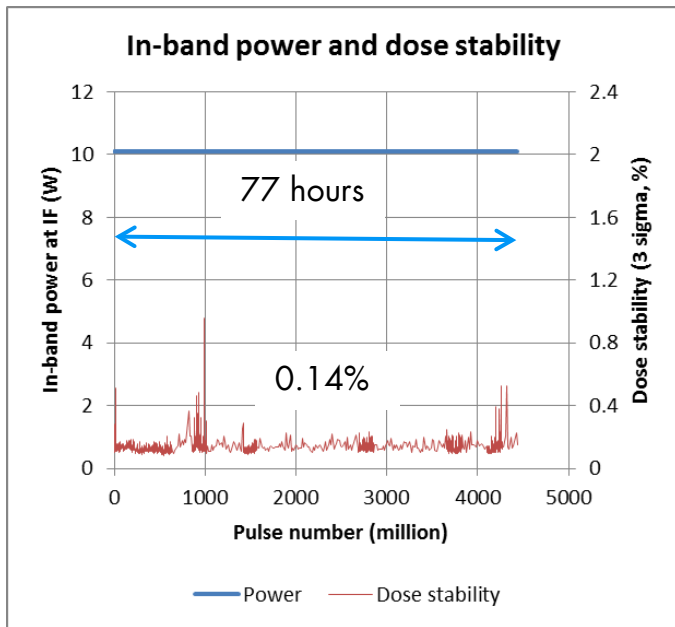


Proto 2 High power Experiment



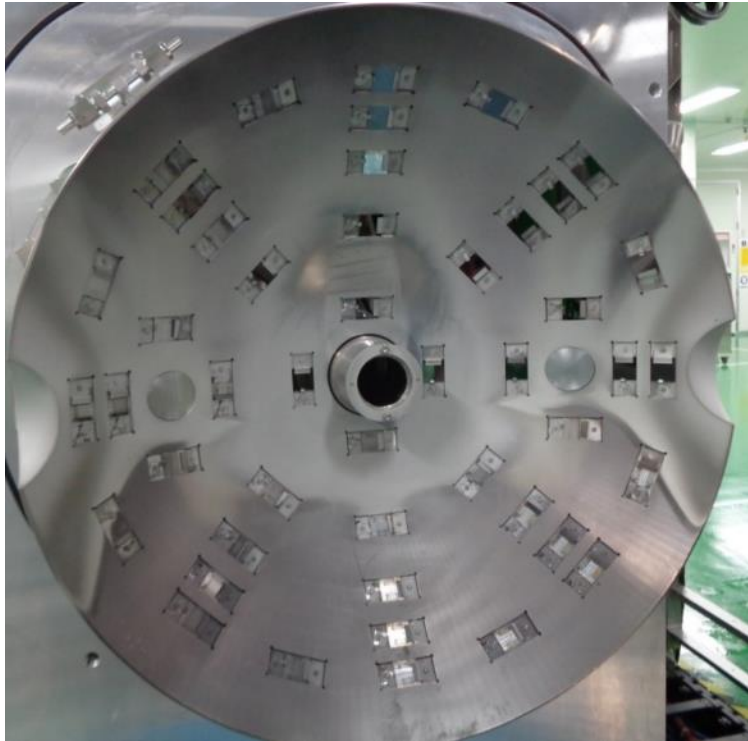
Long Lifetime Operation in Proto#1 System

77 hours operation with 25% dose margin



Proto# 1: Sampling Evaluation

Measurement of Sn deposition distribution at recent Proto# 1 configuration

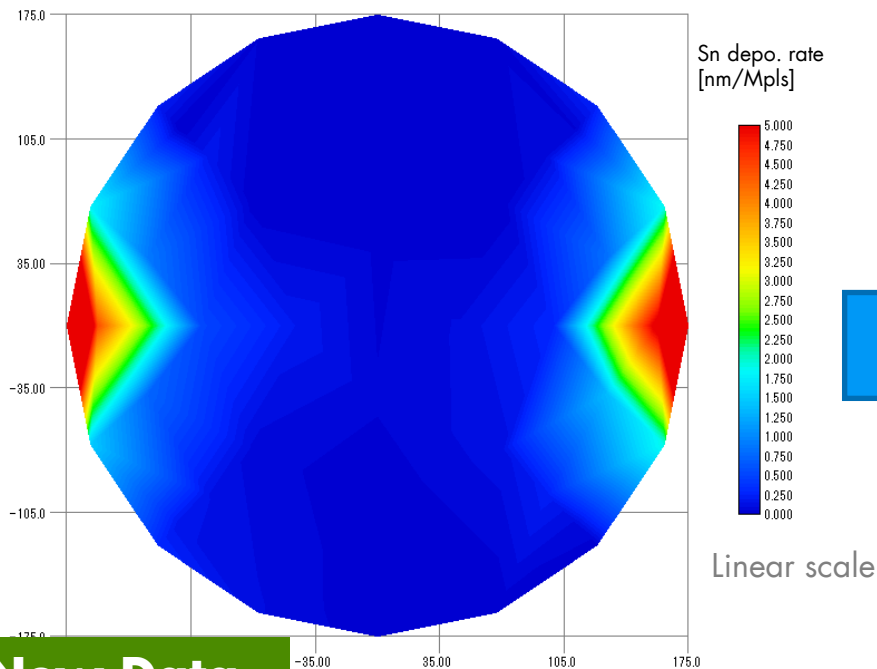


- Purpose
 - » Evaluation of tin deposition distribution on the collector mirror
- Method
 - » dummy collector mirror (no coating)
 - » sampling plate
 - size: 15mmx15mmx0.7mmt
 - material :Si plate (46 pieces)
- Analysis after test
 - » surface condition :SEM
 - » deposited tin thickness :XRF

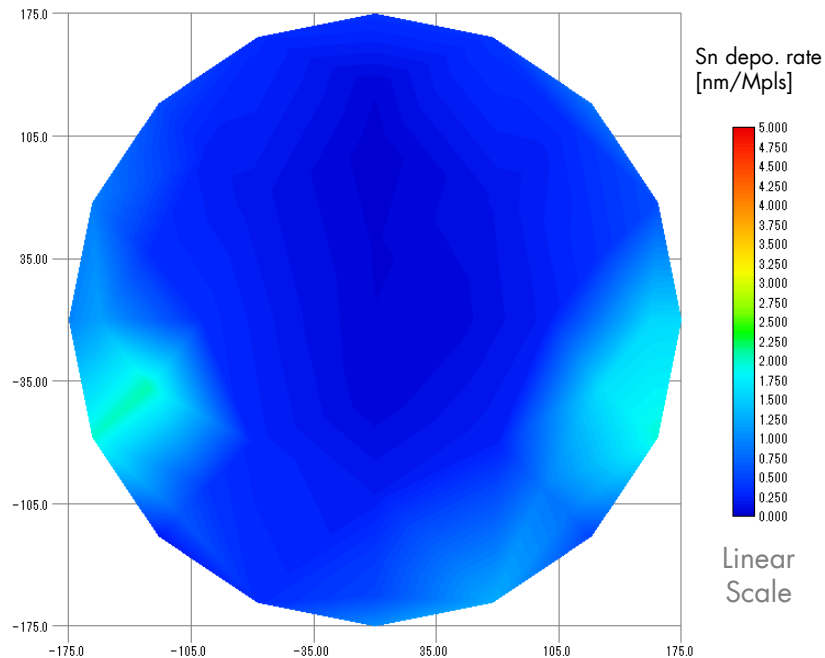
Proto#1: Comparison of tin Deposition Distribution

Mapping of Sn deposition distribution (measured data) at recent Proto#1 configuration

P#1(2015.08)



P#1(2016.01)



New Data

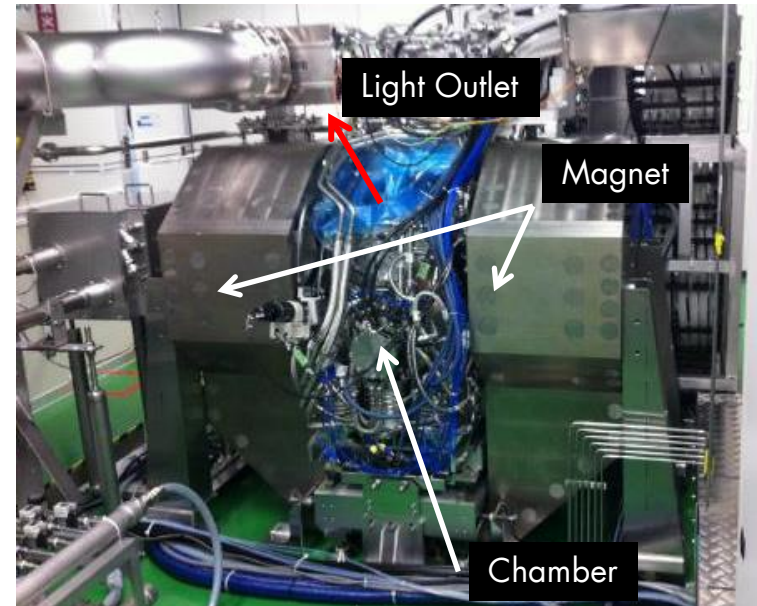
Gigaphoton's High Power EUV Light Source

Prototype high power EUV light source is in operation

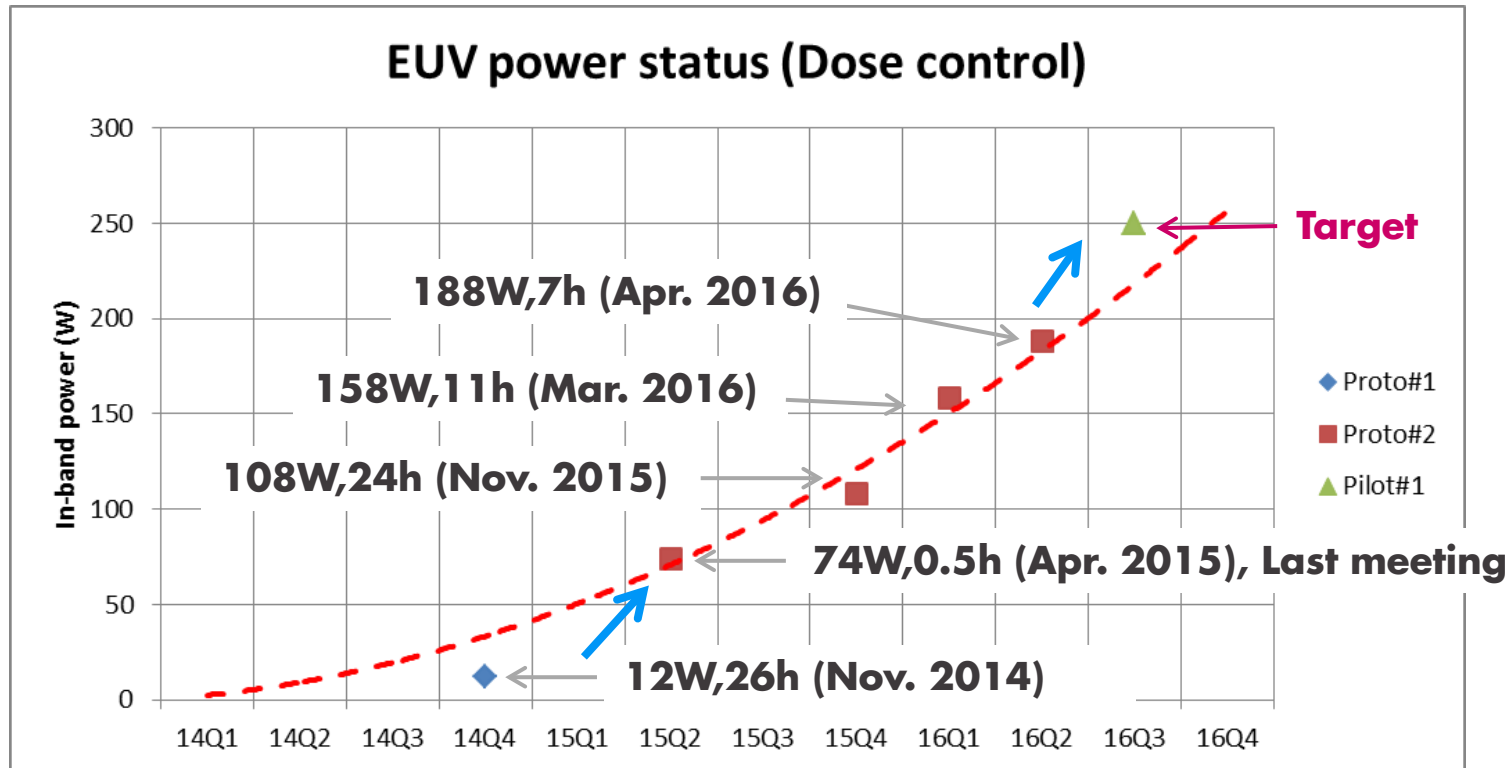
Proto 1 Exposure & Mitigation test



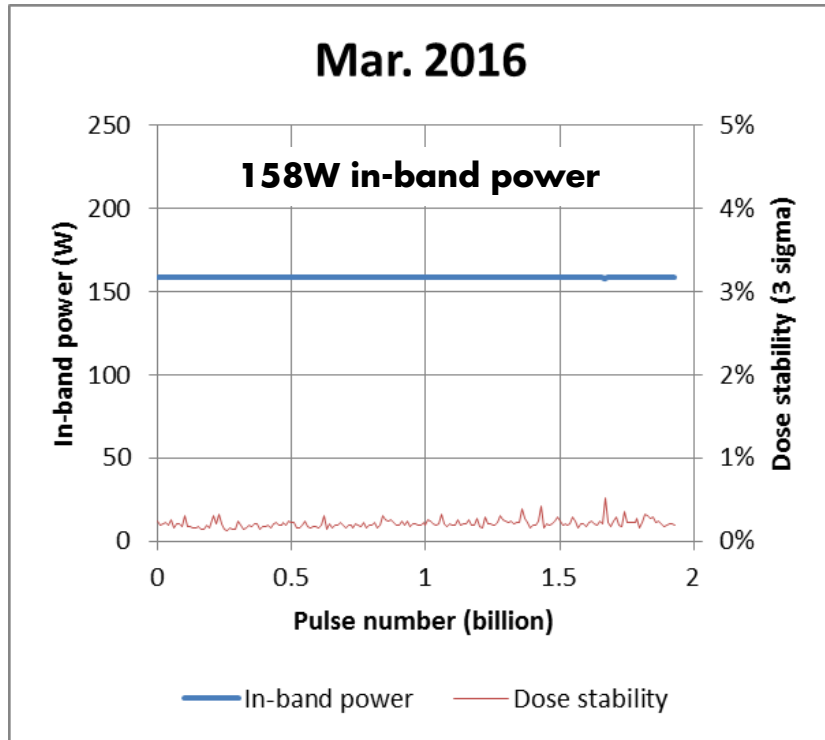
Proto 2 High power Experiment



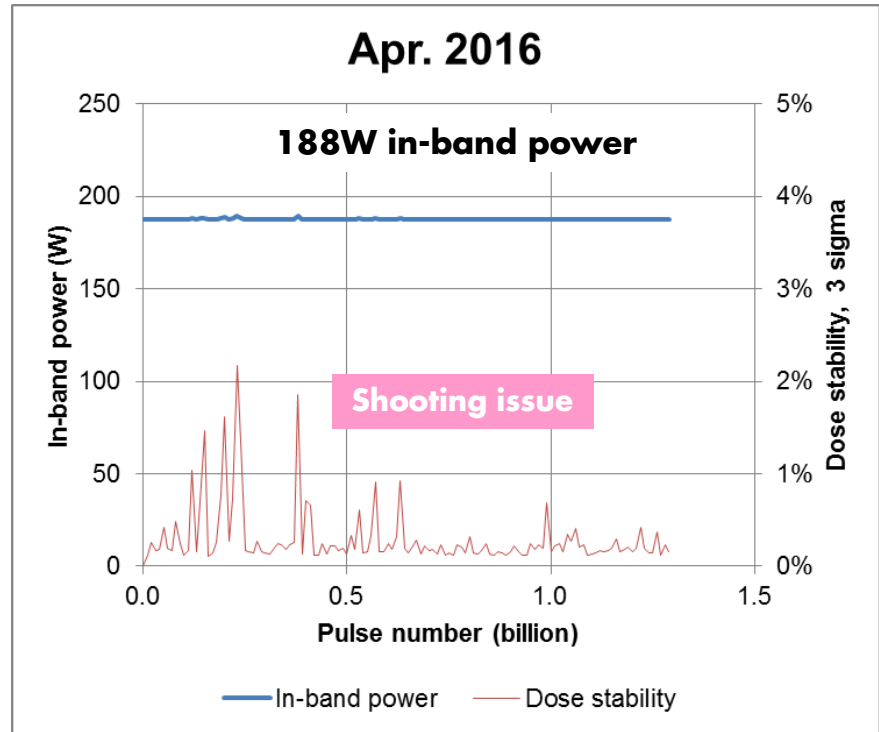
Power Status



High Power Operation (Proto#2)



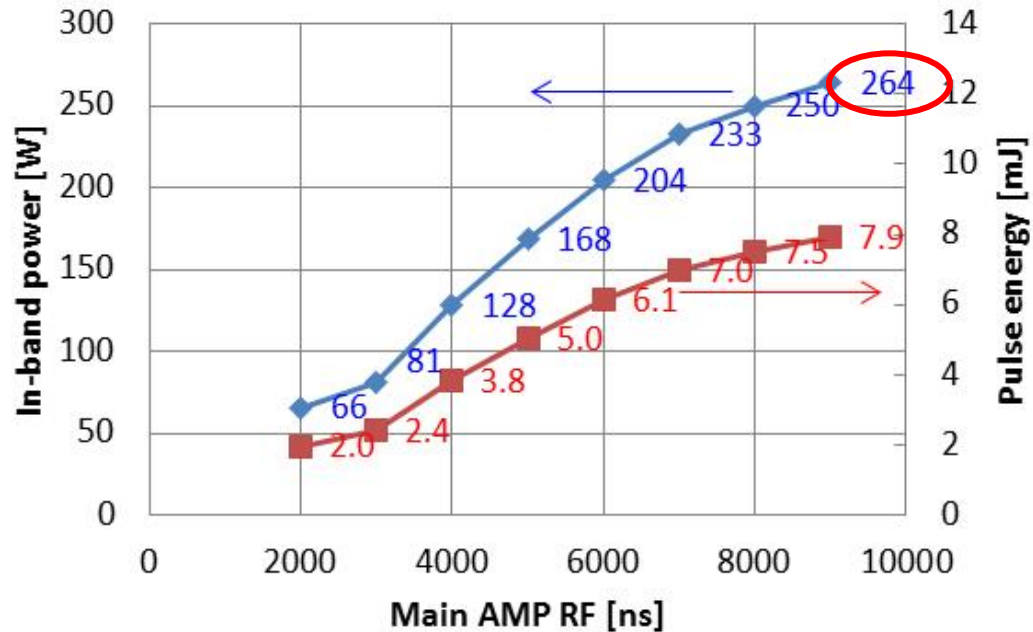
100kHz, 50% duty cycle, 40% dose margin,
Operation time: 11 hours



100kHz, 50% duty cycle, 30% dose margin,
Operation time: 7 hours

Proto #2: Power Data 1 (Mar. 2, 2016 data)

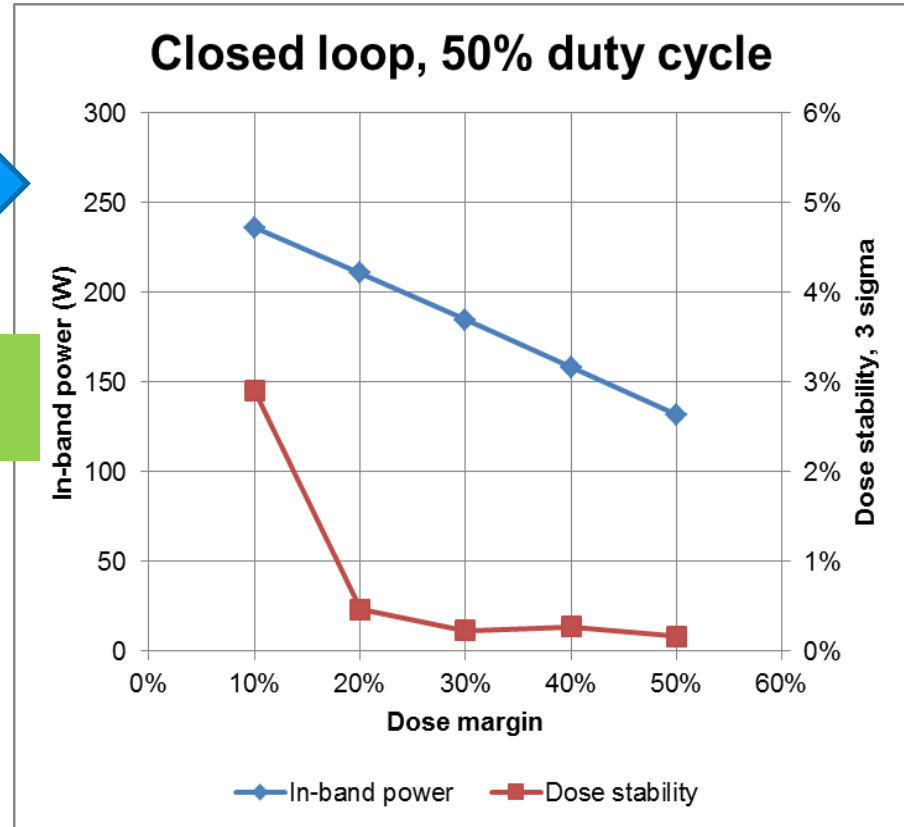
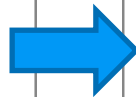
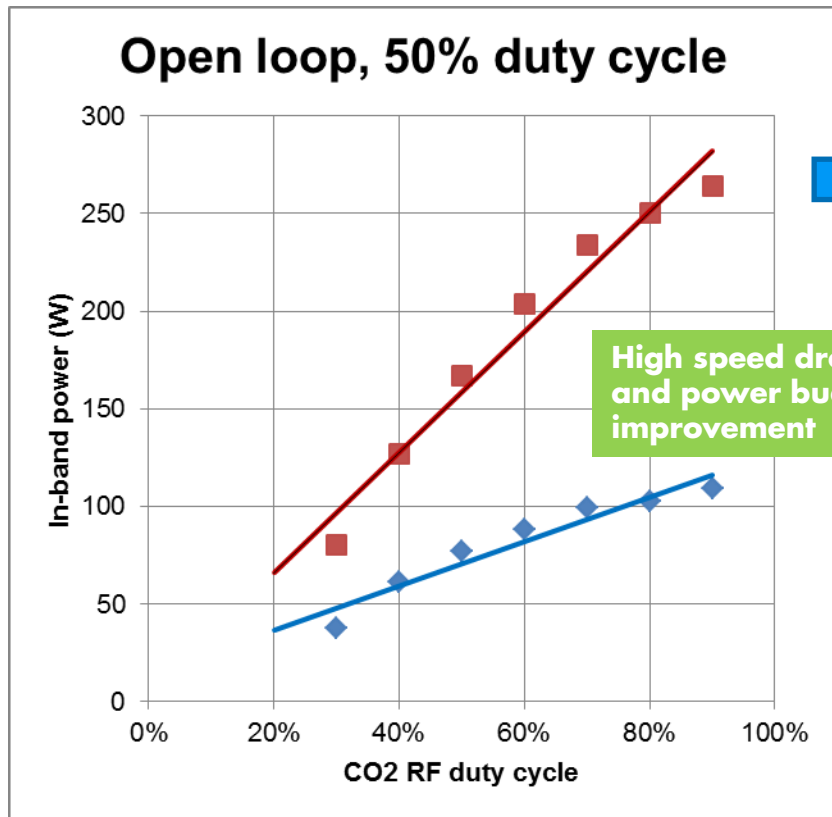
RF - EUV



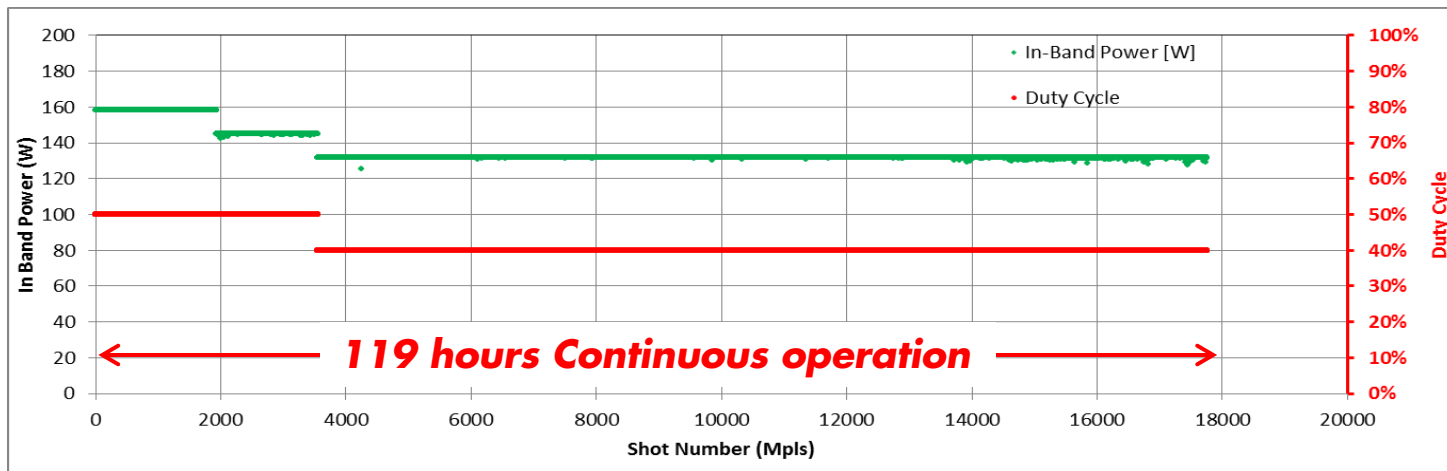
- Maximum power 264W (In-burst)
- Open Loop

New Data

Proto #2: Power Data 2 (Mar. 2, 2016 data)



Proto #2: Power Data 3 (Mar. 3-17, 2016 data)



Result:

In-band power: 158W-132W
 Operation time: 119 h
 Number of Pulse: >17.8 Bpls
 Dose stability 3σ : < 0.19 %

Condition:

Repetition rate: 100kHz
 Duty: 40/50% *
 Average power: 79W-52W
 With dose control mode
 * 10 kpls on/0.15 or 0.1 s off

Technology History and Future Scenario

- 24hours operation with 108W average power was confirmed
- Next target of Proto#2 is 200W、Target of Pilot #1 is 250W, 1week continuous operation until June 2016

	Status				Target		
	Feb 2015	Apr 2014	Dec 2016	Mar 2016	May 2016	Jun 2016	Dec 2016
System	Proto#1	Proto#2	Proto#2	Proto#2	Proto#2	Pilot#1	Pilot#1
In band power	10W	74W	108W	158/132W	200W	250W	250W
Average power at IF dose control	8W	70W	54W	79/52W	100W	250W	250W
Operation time	77hour	0.5hour	24hour	119hour	> 100hour	>1week	>1month
Duty cycle	80%	95%	50%	50/40%	>50%	100%	100%
Repetition rate	20kHz	35kHz	80kHz	100kHz	100kHz	100kHz	100kHz
CO2 power at plasma	1.1kW	10kW	14kW	15kW	17kW	>23kW	>23kW
CE	3.2%	3.2%	3.5%	3.5%	3.5%	4.0%	4.0%
Power budget from plasma to IF	31.6%	31.6%	31.6%	31.6%	31.6%	35.1%	35.1%
Dose margin	25%	20%	40%	40%	20%	20%	20%
Availability based on 24x7	13.5%	5.3%	>20%	>30%	>50%	>60%	>90%

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Extendibility to 500W EUV Power

Possible scale up scenario of EUV Output Power vs. CO₂ Input Power

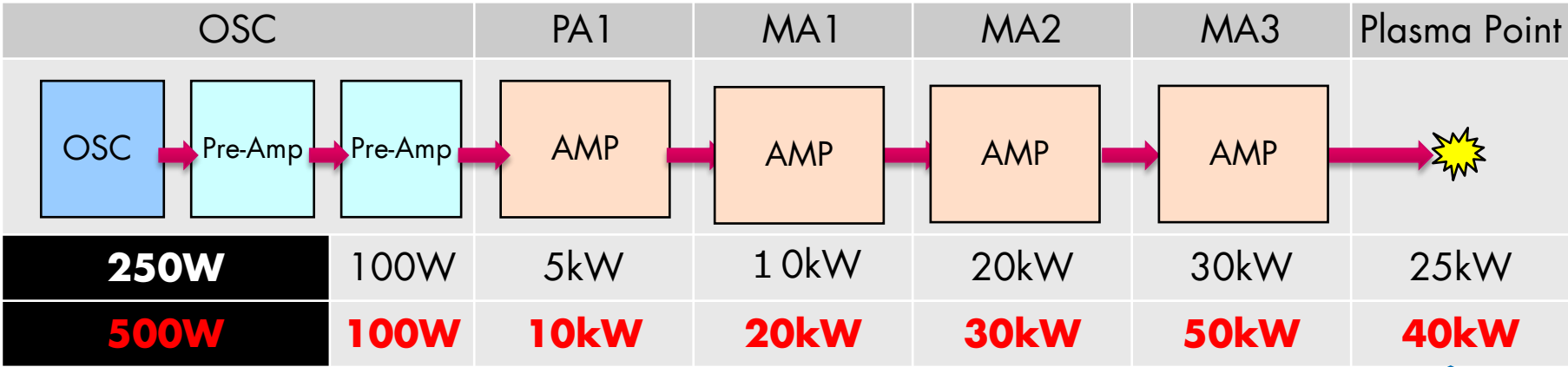
EUV ave.Power[W] @100kHz		Conversion Efficiency [%]							
		2%	3%	4%	5%	6%	7%	8%	
15	1.5	0.0	0.0	0.0	0.0	0.0	0.0	0.0	
50	5	19.1	28.7	38.2	47.8	57.3	66.9	76.4	
100	10	46.4	69.6	92.8	116.0	139.2	162.4	185.6	
150	15	73.7	110.6	147.4	184.3	221.1	258.0	294.8	
200	20	101.0	151.5	202.0	252.5	303.0	353.5	404.0	
250	25	128.3	192.5	256.6	320.8	384.9	449.1	513.2	
300	30	155.6	233.4	311.2	389.0	466.8	544.6	622.4	
350	35	182.9	274.4	365.8	457.3	548.7	640.2	731.6	
400	40	210.2	315.3	420.4	525.5	630.6	735.7	840.8	
450	45	237.5	356.3	475.0	593.8	712.5	831.3	950.0	
500	50	264.8	397.2	529.6	662.0	794.4	926.8	1059.2	
550	55	292.1	438.2	584.2	730.3	876.3	1022.4	1168.4	
600	60	319.4	479.1	638.8	798.5	958.2	1117.9	1277.6	
650	65	346.7	520.1	693.4	866.8	1040.1	1213.5	1386.8	
700	70	374.0	561.0	748.0	935.0	1122.0	1309.0	1496.0	
750	75	401.3	602.0	802.6	1003.3	1203.9	1404.6	1605.2	
800	80	428.6	642.9	857.2	1071.5	1285.8	1500.1	1714.4	
850	85	455.9	683.9	911.8	1139.8	1367.7	1595.7	1823.6	
900	90	483.2	724.8	966.4	1208.0	1449.6	1691.2	1932.8	
950	95	510.5	765.8	1021.0	1276.3	1531.5	1786.8	2042.0	
1000	100	537.8	806.7	1075.6	1344.5	1613.4	1882.3	2151.2	

Our possible scale-up scenario

	HVM (1 st)	HVM (2 nd)	HVM (3 rd)
EUV power	250W	500W	1000W
Pulse Rate	100 kHz	100kHz	100kHz
CE	4%	5%	6%
CO ₂ Laser Power	25kW	40kW	65kW

High Power CO₂ Laser System

Carbolated with  MITSUBISHI ELECTRIC



<History of Amplifier development>

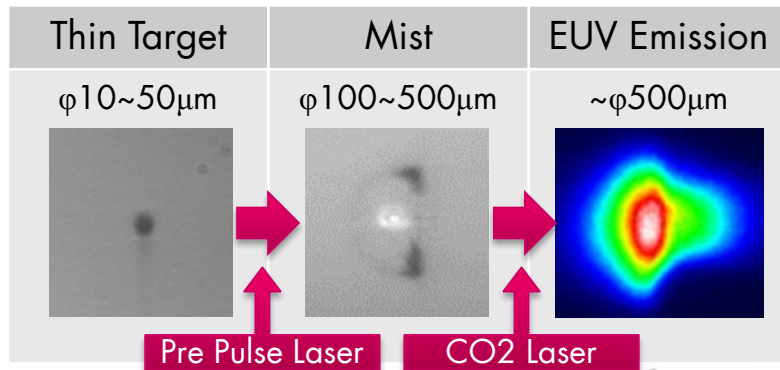


High EUV Conversion Efficiency

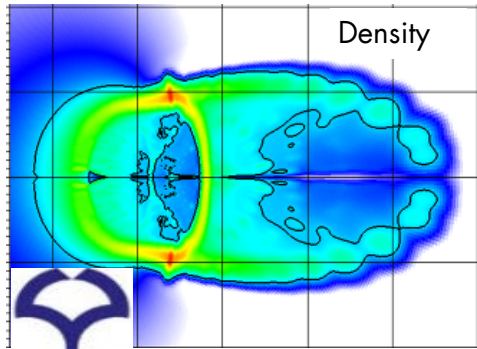
Cooperation with



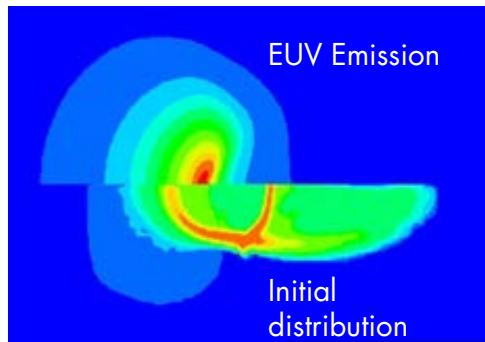
	CO2 Pulse Energy	Ce	EUV Energy	Density
250W	250mJ	4%	10mJ	>0.3J/mm ³
500W	360mJ	5%	18mJ	>0.5J/mm ³



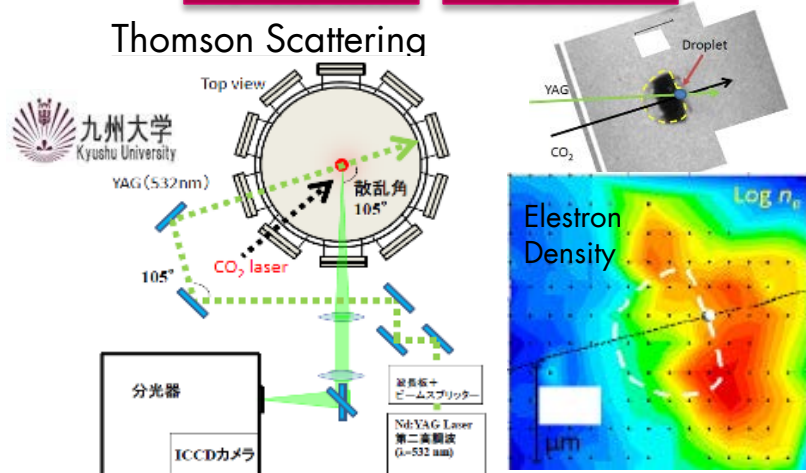
Target Simulation



Simulation of EUV Emission



Thomson Scattering



AGENDA

- Introduction
- Issue of EUV Light Source and History of Source Power-Up
- 250W Pilot System Development Update
 - Key Component Technologies Update
- Prototype LPP Source Systems Experiment Update
 - Proto Device #1
 - Proto Device #2
- For Future Development of 500W LPP Source
- **Summary**

Summary

- Recent Topics of LPP Source component technologies are reported.
- **Pilot #1 is starting operation**
 - » Construction has finished at Feb. 2016.
 - » Now we are starting CO2 driver laser power test up to 20kW .
 - » First data will be expected in July 2016.
- Progress of Proto #1 unit
 - » Further improvement of “Magnetic debris mitigation”
 - » Magnetic mitigation capability is discussed by using Tin distribution measurement.
 - » Up time is improved dramatically current 6 month. Utilize test for EIDEC
- Progress of Proto #2 unit
 - » **264W in-bound Power was demonstrated.**
 - » **119 hours 158-132 W power (in burst) under closed loop stable operation was successfully demonstrated**
- Discussion of 500W Light Source

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